

MBRH12020 thru MBRH12040R

Silicon Power Schottky Diode

 $V_{RRM} = 20 V - 40 V$

 $I_{F(AV)} = 120 A$

Features

- High Surge Capability
- Types from 20 V to 40 V V_{RRM}
- Not ESD Sensitive



Common Cathode





D-67 Package





Maximum ratings, at T_i = 25 °C, unless otherwise specified ("R" devices have leads reversed)

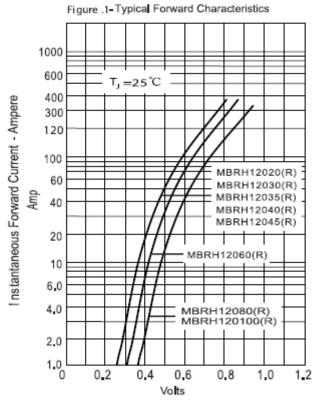
Parameter	Symbol	Conditions	MBRH12020(R)	MBRH12030(R)	MBRH12035(R)	MBRH12040(R)	Unit
Repetitive peak reverse voltage	V_{RRM}		20	30	35	40	V
RMS reverse voltage	V_{RMS}		14	21	25	28	V
DC blocking voltage	V_{DC}		20	30	35	40	V
Operating temperature	Tj		-55 to 150	-55 to 150	-55 to 150	-55 to 150	°C
Storage temperature	T_{stg}		-55 to 150	-55 to 150	-55 to 150	-55 to 150	°C

Electrical characteristics, at Tj = 25 °C, unless otherwise specified

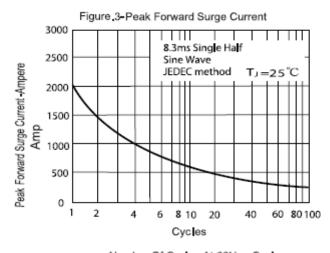
Parameter	Symbol	Conditions	MBRH12020(R)	MBRH12030(R)	MBRH12035(R)	MBRH12040(R)	Unit	
Average forward current (per pkg)	I _{F(AV)}	T _C = 125 °C	120	120	120	120	Α	
Peak forward surge current	I _{FSM}	t_p = 8.3 ms, half sine	2000	2000	2000	2000	Α	
Maximum instantaneous forward voltage	V _F	I _{FM} = 120 A, T _j = 25 °C	0.70	0.70	0.70	0.70	V	
Maximum instantaneous		T _j = 25 °C	1	1	1	1		
reverse current at rated DC	I_R	$T_j = 100 ^{\circ}C$	10	10	10	10	mA	
blocking voltage		T _j = 150 °C	30	30	30	30		
Thermal characteristics								
Thermal resistance, junction- case	R _{oJC}		0.48	0.48	0.48	0.48	°C/W	



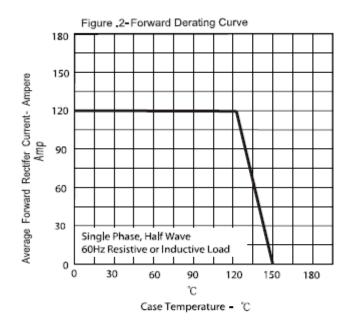
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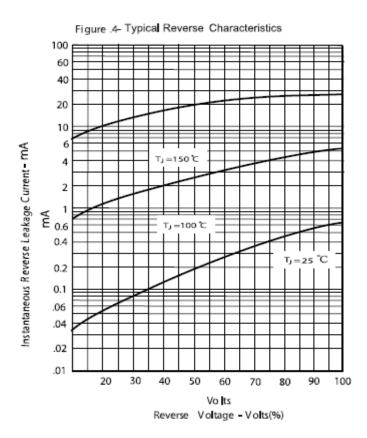






Number Of Cycles At 60Hz - Cycles

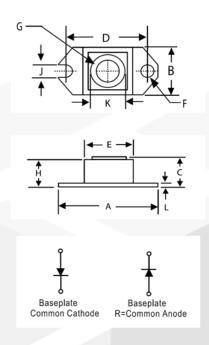




MBRH12020 thru MBRH12040R

Package dimensions and terminal configuration

Product is marked with part number and terminal configuration.



DIME NS IONS								
DIM	INCH	IES	М	NOTE				
	MIN	MAX	MIN	MAX				
Α	1.515	1.560	38.48	39.62				
В	.725	.775	18.42	19.69				
C	.595	.625	15.11	15.88				
D	1.182 1.192		30.02	30.28				
E	.736 .744		18.70	18.90				
F	.152	.160	3.86	4.061	Ø			
G								
Н	.540	.580	13.72	14.73				
J	.156	.160	3.96	4.06				
K	.480	.492	12.20	12.50	Ø			
L	.120	.130	3.05	3.30				

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M252511FV DD2	260N12K-A	DD380N16A	DD89N1600K-	$\underline{\mathbf{A}}$ $\underline{\mathbf{APT2X21D0}}$	C60J <u>APT58M</u>	80J B522F-2-Y	YEC MSTC90-1	6 25.163.0653.1
<u>25.163.2453.0</u> <u>25.</u>	163.4253.0	25.190.2053.0	25.194.3453.0	25.320.4853.1	25.320.5253.1	25.326.3253.1	25.326.3553.1	25.330.1653.1
<u>25.330.4753.1</u> <u>25.</u>	330.5253.1	25.334.3253.1	25.334.3353.1	25.350.2053.0	25.352.4753.1	25.522.3253.0	<u>T483C</u> <u>T484C</u>	T485F T485H
T512F-YEB T513	<u>F T514F T</u>	<u>T612FSE</u>	25.161.3453.0	25.179.2253.0	25.194.3253.0	25.325.1253.1	25.326.4253.1	25.330.0953.1
<u>25.332.4353.1</u> <u>25.</u>	350.1653.0	25.350.2453.0	25.352.1453.0	25.352.1653.0	25.352.2453.0	25.352.5453.1	25.522.3353.0	25.602.4053.0
25.640.5053.0								